

# ES1A THRU ES1M

## Features

- Halogen free available upon request by adding suffix "-HF"
- Lead Free Finish/Rohs Compliant (Note1) ("P" Suffix designates Compliant. See ordering information)
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1
- High Temp Soldering: 260°C for 10 Seconds At Terminals
- Superfast Recovery Times For High Efficiency

## Maximum Ratings

- Operating Temperature: -50°C to +150°C
- Storage Temperature: -50°C to +150°C
- Maximum Thermal Resistance; 15°C/W Junction To Lead

Part Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
ES1A	ES1A	50V	35V	50V
ES1B	ES1B	100V	70V	100V
ES1C	ES1C	150V	105V	150V
ES1D	ES1D	200V	140V	200V
ES1G	ES1G	400V	280V	400V
ES1J	ES1J	600V	420V	600V
ES1K	ES1K	800V	560V	800V
ES1M	ES1M	1000V	700V	1000V

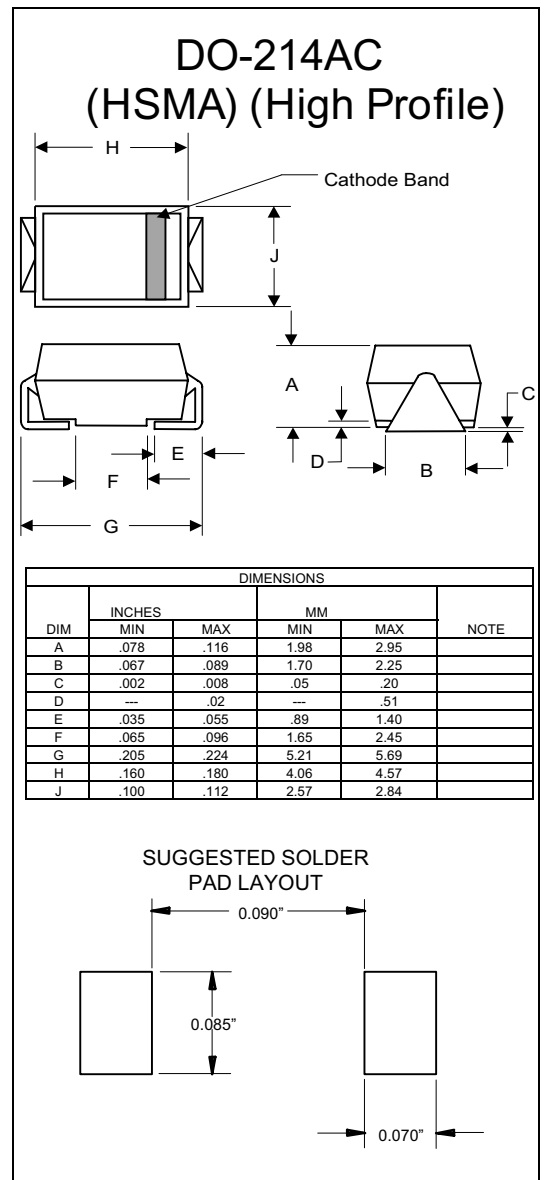
## Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_a = 75^\circ\text{C}$
Peak Forward Surge Current	$I_{FSM}$	30A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	$V_F$	ES1A-D: .975V ES1G-J: 1.35V ES1K~M: 1.70V	$I_{FM} = 1.0A$ ; $T_J = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	$I_R$	5 $\mu\text{A}$ 100 $\mu\text{A}$	$T_J = 25^\circ\text{C}$ $T_J = 100^\circ\text{C}$
Maximum Reverse Recovery Time	$T_{rr}$	ES1A-D: 50ns ES1G-K: 75ns ES1M: 100ns	$I_F = 0.5A$ , $I_R = 1.0A$ , $I_{rr} = 0.25A$
Typical Junction Capacitance	$C_J$	45pF	Measured at 1.0MHz, $V_R = 4.0V$

\*Pulse test: Pulse width 200  $\mu\text{sec}$ , Duty cycle 2%

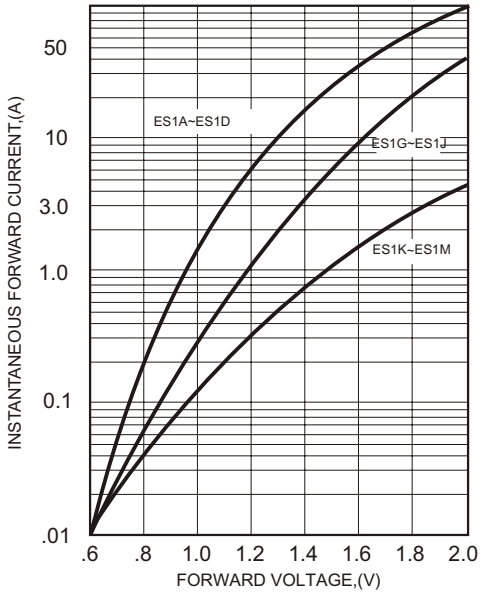
Note: 1. High Temperature Solder Exemptions Applied, see EU Directive Annex 7.

## 1 Amp Ultra Fast Recovery Silicon Rectifier 50 to 1000 Volts



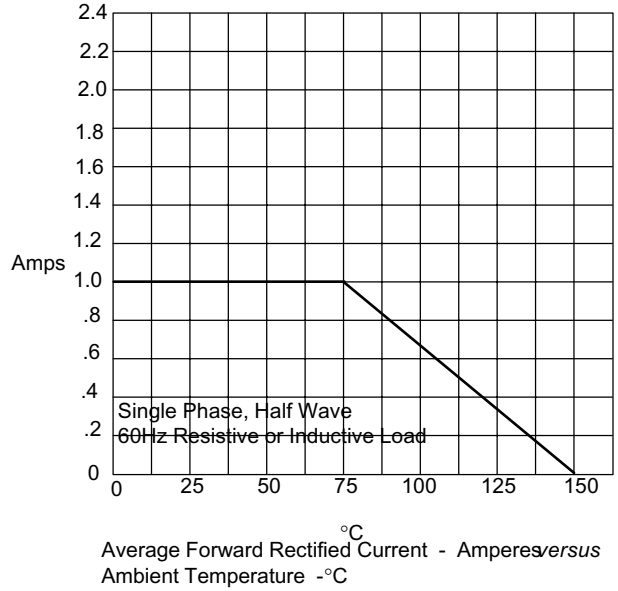
# ES1A thru ES1M

Figure 1  
Typical Forward Characteristics



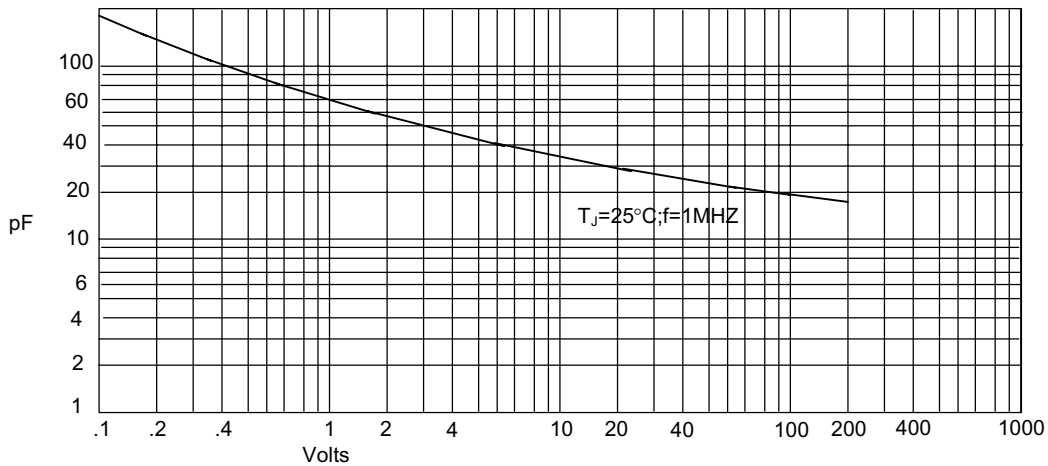
Instantaneous Forward Current - Amperes versus  
Instantaneous Forward Voltage - Volts

Figure 2  
Forward Derating Curve



Average Forward Rectified Current - Amperes versus  
Ambient Temperature - °C

Figure 3  
Junction Capacitance

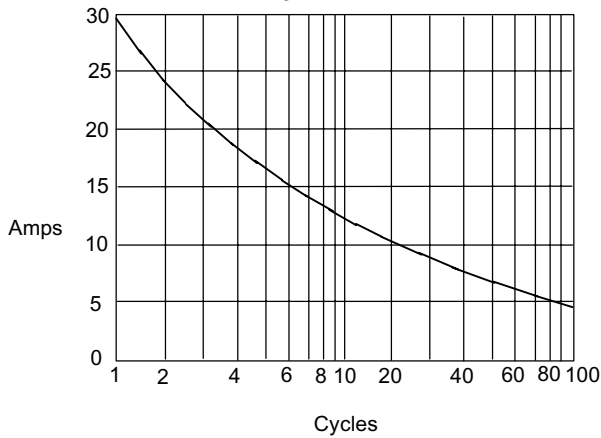


Junction Capacitance - pF versus  
Reverse Voltage - Volts



# ES1A thru ES1M

Figure 4  
Peak Forward Surge Current



Peak Forward Surge Current - Amperes versus  
Number Of Cycles At 60Hz - Cycles

Figure 5  
Typical Reverse Characteristics

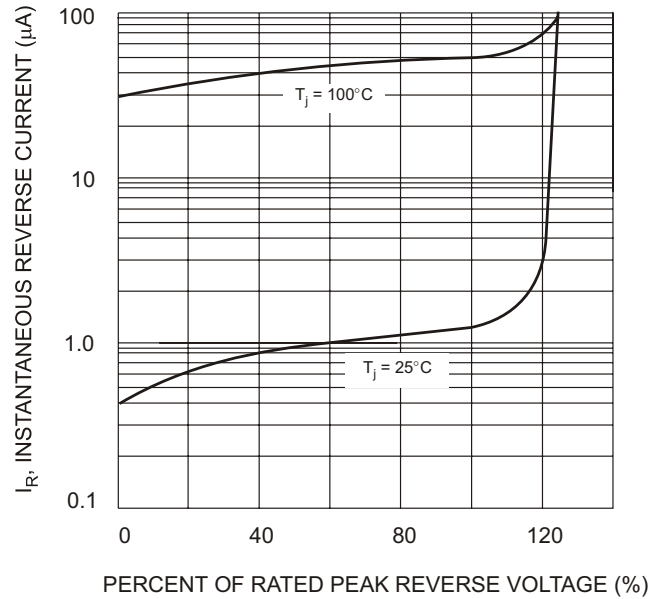
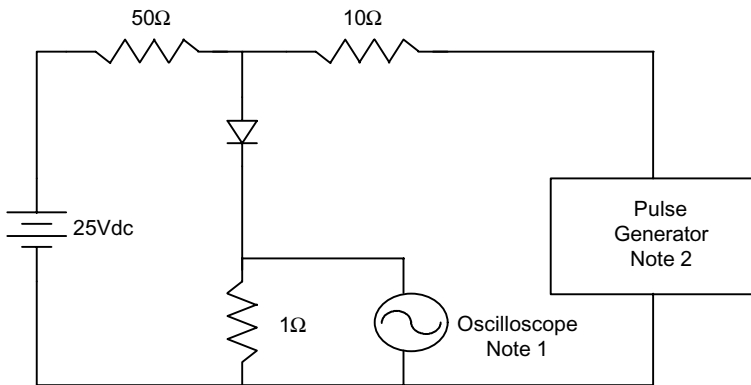


Figure 6  
Reverse Recovery Time Characteristic And Test Circuit Diagram



- Notes:
1. Rise Time = 7ns max.  
Input impedance = 1 megohm, 22pF
  2. Rise Time = 10ns max.  
Source impedance = 50 ohms
  3. Resistors are non-inductive

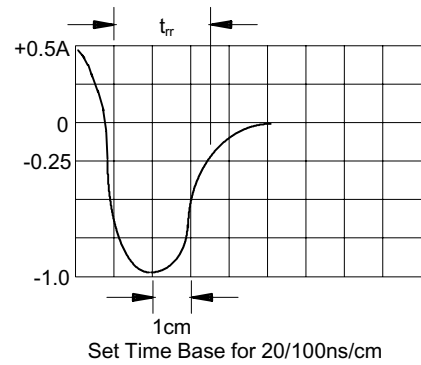


Figure 7  
New SMA Assembly

